BT136X series D

GENERAL DESCRIPTION

Glass passivated, sensitive gate triacs in a full pack plastic envelope, intended for use in general purpose bidirectional switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

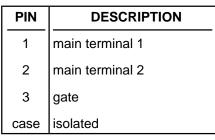
PINNING - SOT186A

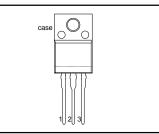
QUICK REFERENCE DATA

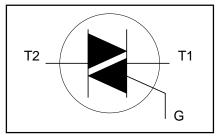
| SYMBOL | PARAMETER | MAX. | MAX. | UNIT |
|---|---|-------------------------------|------------------------|-------------|
| V _{drm} I _{t(rms)} I _{tsm} | BT136X- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current | 500D 500 4 25 | 600D 600 4 25 | V A A |

PIN CONFIGURATION

SYMBOL







LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MA | AX. | UNIT |
|--|---|---|----------|---------------------------------|---------------------------------|-----------------------|
| V _{drm} | Repetitive peak off-state voltages | | - | -500 500 ¹ | -600 600 ¹ | V |
| I _{T(RMS)} I _{TSM} | RMS on-state current Non-repetitive peak on-state current | full sine wave; $T_{hs} \le 92 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge | - | | 4 | A |
| | | t = 20 ms | - | 2 | 5 | A |
| l ² t | 1 ² t for fusing | t = 16.7 ms t = 10 ms | - | 3 | 7 | A A ² s |
| dl _T /dt | I ² t for fusing Repetitive rate of rise of on-state current after | $I_{TM} = 6 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$ | - | S | . I | AS |
| | triggering | T2+ G+ | - | | 0 | A/μs |
| | | T2+ G- | - | | 0 | A/µs |
| | | T2- G- | - | | 0 | A/μs |
| | | T2- G+ | - | 1 | 0 | A/µs |
| I _{GM} V _{GM} | Peak gate current | | - | | 2 | A |
| V _{GM} | Peak gate voltage | | - | | 5 | V W |
| P _{GM} | Peak gate power Average gate power | over any 20 ms period | - | | .5 | Ŵ |
| $\begin{array}{c} P_{G(AV)}^{G(AV)} \\ T_{stg} \\ T_{j} \end{array}$ | Storage temperature Operating junction temperature | over any 20 ms period | -40 - | 1: | 50 25 | °°, |

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 $A/\mu s$.

| Triacs | | |
|-------------|--|--|
| logic level | | |

BT136X series D

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|-------------------|--|--|------|------|------|------|
| V _{isol} | R.M.S. isolation voltage from all three terminals to external heatsink | f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree | - | | 2500 | V |
| C _{isol} | Capacitance from T2 to external heatsink | f = 1 MHz | - | 10 | - | рF |

THERMAL RESISTANCES

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---|---|--|-------------|--------------|-----------------|-------------------|
| R _{th j-hs} R _{th j-a} | Thermal resistance junction to heatsink Thermal resistance junction to ambient | full or half cycle with heatsink compound without heatsink compound in free air | - - - | - - 55 | 5.5 7.2 - | K/W K/W K/W |

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

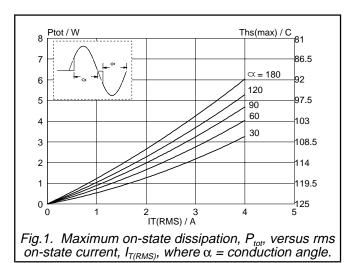
| SYMBOL | PARAMETER | CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|----------------------|---------------------------|--|--------|------|------|------|------|
| I _{GT} | Gate trigger current | $V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$ | | | | | |
| 01 | | | T2+ G+ | - | 2.0 | 5 | mA |
| | | - | T2+ G- | - | 2.5 | 5 | mA |
| | | - | T2- G- | - | 2.5 | 5 | mA |
| | | | T2- G+ | - | 5.0 | 10 | mA |
| I, | Latching current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | | | | | |
| - | | | T2+ G+ | - | 1.6 | 10 | mA |
| | | - | T2+ G- | - | 4.5 | 15 | mA |
| | | - | T2- G- | - | 1.2 | 10 | mA |
| | | - | T2- G+ | - | 2.2 | 15 | mA |
| I _H | Holding current | $V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$ | | - | 1.2 | 10 | mA |
| I _H V⊤ | On-state voltage | $I_{T} = 5 A$ | | - | 1.4 | 1.70 | V |
| V _{GT} | Gate trigger voltage | $\dot{V}_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$ | | - | 0.7 | 1.5 | V |
| | | $V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125^{\circ}$ | С | 0.25 | 0.4 | - | V |
| I _D | Off-state leakage current | $V_{D}^{i} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 125 \text{ °V}$ $V_{D} = V_{DRM(max)}; T_{j} = 125 \text{ °C}$ | | - | 0.1 | 0.5 | mA |

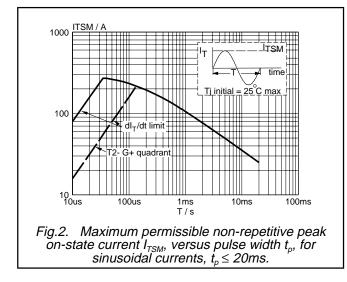
DYNAMIC CHARACTERISTICS

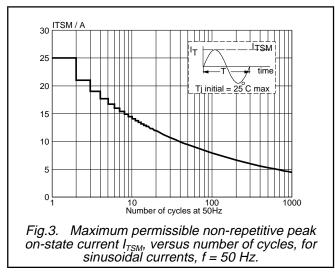
 $T_j = 25$ °C unless otherwise stated

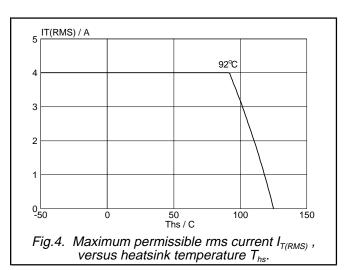
| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------|--|--|------|------|------|------|
| dV _D /dt | Critical rate of rise of off-state voltage | $V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 1 k\Omega$ | - | 5 | - | V/μs |
| t _{gt} | | $I_{TM} = 6 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A}; $ $dI_G/dt = 5 \text{ A/}\mu\text{s}$ | - | 2 | - | μs |

BT136X series D









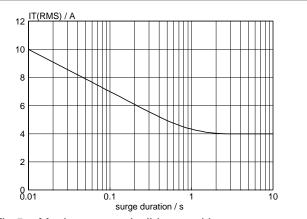
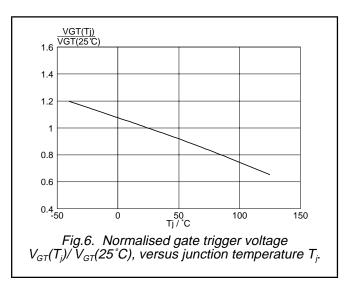
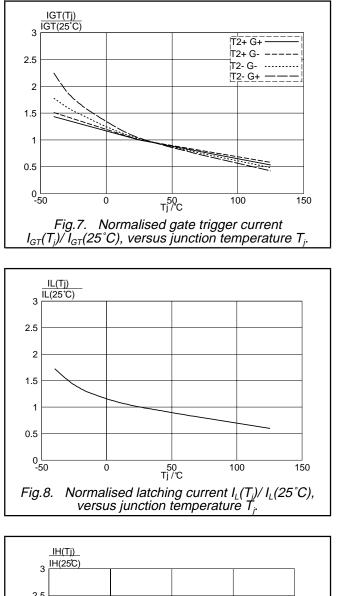
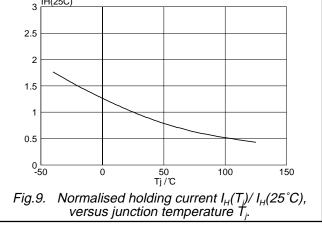


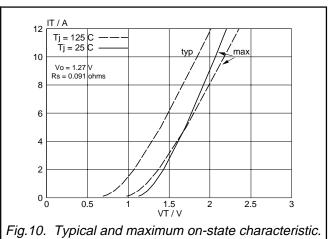
Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{hs} \le 92^{\circ}C$.

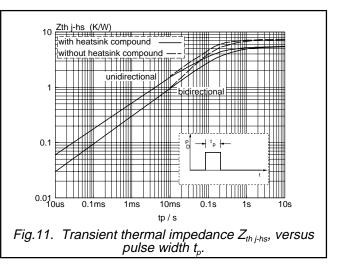


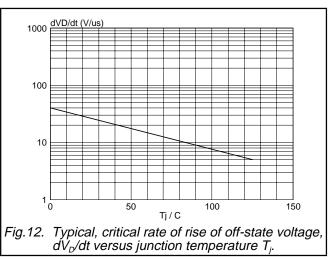
BT136X series D





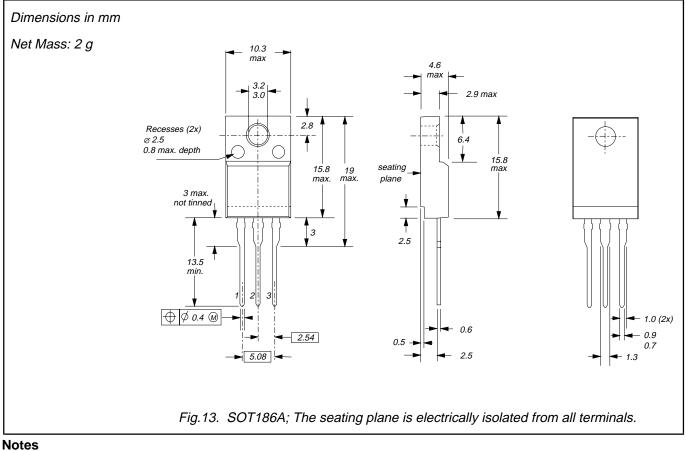






BT136X series D

MECHANICAL DATA



Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

| Triacs | BT136X series D |
|-------------|-----------------|
| logic level | |

DEFINITIONS

| Data sheet status | | | | | |
|--|---|--|--|--|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | | | | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | | | | |
| Product specification | This data sheet contains final product specifications. | | | | |
| Limiting values | | | | | |
| Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | | | | |
| Application information | | | | | |
| Where application information is given, it is advisory and does not form part of the specification. | | | | | |

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